



60V NPN MEDIUM POWER LOW SATURATION TRANSISTOR IN SOT223

Description

Features

This bipolar junction transistor (BJT) is designed to meet the stringent requirements of automotive applications.

Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic. "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish—Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.112 grams (Approximate)

Applications

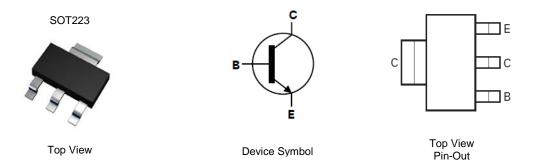
- Emergency Lighting Circuits
- MOSFET & IGBT Gate Drivers
- Solenoid, Relay and Actuator Drivers
- DC Modules
- Motor Control

I_C = 6A High Continuous Collector Current
 I_{CM} = 20A Peak Pulse Current

 $BV_{CEO} > 60V$

- ICM = 20A Feak Fulse Cullent
 Low Cotynetics Valtage V
- Low Saturation Voltage V_{CE(sat)} < 60mV @ 1A
- $R_{SAT} = 35m\Omega$ for a Low Equivalent On-Resistance
- hFE Specified up to 10A for High Gain Hold-Up
- Complementary PNP Type: ZX5T951GQ
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen- and Antimony-Free. "Green" Device (Note 3)
- The ZX5T851GQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF16949 certified facilities.

https://www.diodes.com/quality/product-definitions/



Ordering Information (Note 4)

Product	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
ZX5T851GQTC	Automotive	X5T851	13	12	4000

Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and

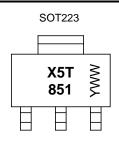
2. See https://www.diodes.com/quality/lead-tree/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-tree, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.



Marking Information



X5T 851 = Product Type Marking Code YWW = Date Code Marking Y or \overline{Y} = Last Digit of Year (ex: 0= 2020) WW or $\overline{W}W$ = Week Code (01~53)

Absolute Maximum Ratings (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	150	V
Collector-Emitter Voltage	V _{CEO}	60	V
Emitter-Base Voltage	V _{EBO}	7	V
Continuous Collector Current	Ic	6	A
Peak Pulse Current	I _{CM}	20	A

Thermal Characteristics (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
	(Note 5)		3.0		
Dower Dissinction	(Note 6)		2.0	w	
Power Dissipation	(Note 7)	PD	1.6	vv	
	(Note 8)		1.2		
	(Note 5)		41.7		
Thermal Desistance, Junction to Ambient	(Note 6)	P. I	62.5		
Thermal Resistance, Junction to Ambient	(Note 7)	R _θ JA	78.1	°C/W	
	(Note 8)		104		
Thermal Resistance Junction to Lead	(Note 9)	R _{θJL}	10.5		
Dperating and Storage Temperature Range	T _{J,} T _{STG}	-55 to +150	°C		

ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4000	V	ЗA
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes: 5. For a device mounted with the collector lead on 50mm x 50mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

6. Same as Note 5 except the device is mounted on 25mm x 25mm 2oz copper.

7. Same as Note 5 except the device is mounted on 25mm x 25mm 1oz copper.

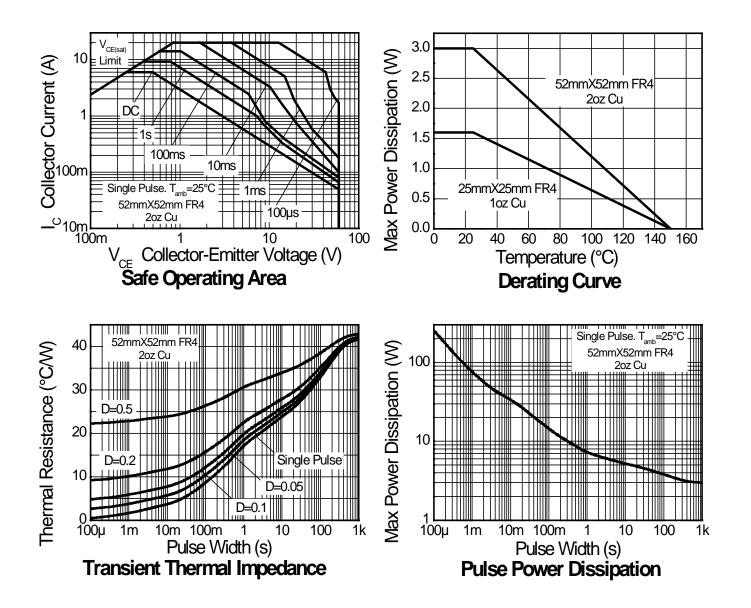
8. Same as Note 5 except the device is mounted on minimum recommended pad layout.

9. Thermal resistance from junction to solder-point (at the end of the collector lead).

10. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information





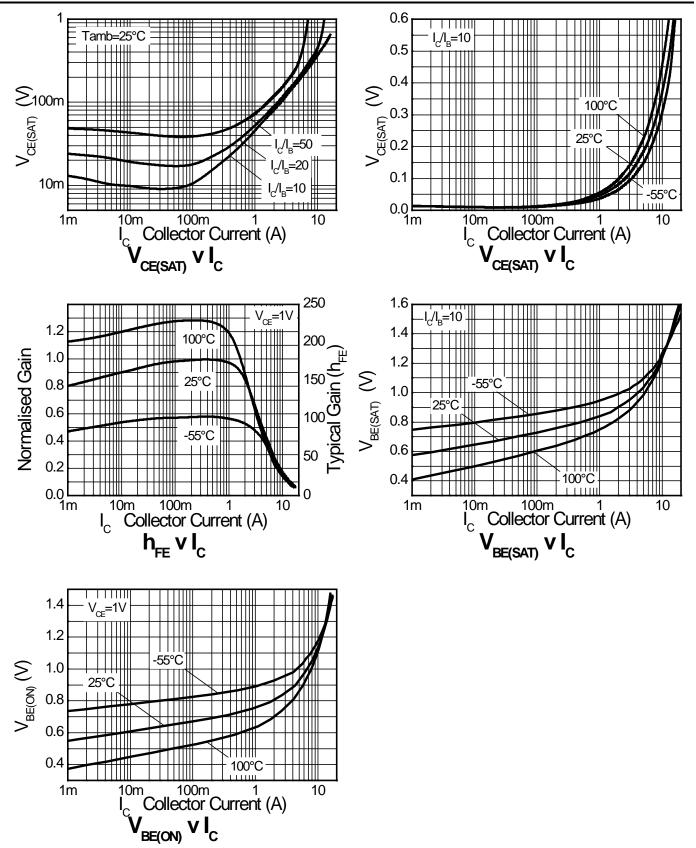
Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	150	190	—	V	I _C = 100μA
Collector-Emitter Breakdown Voltage	BV _{CER}	150	190	—	V	$I_{C} = 1\mu A, R_{B} \le 1k\Omega$
Collector-Emitter Breakdown Voltage (Note 11)	BV _{CEO}	60	80	—	V	$I_{\rm C} = 10 {\rm mA}$
Emitter-Base Breakdown Voltage	BV _{EBO}	7	8.1	—	V	$I_E = 100 \mu A$
Collector Cut-Off Current	I _{CBO}		<1 —	20 0.5	nΑ μΑ	V _{CB} = 120V V _{CB} = 120V, T _A = +100°C
Collector Cut-Off Current	l _{CER} R _B ≤ 1kΩ	_	<1 —	20 0.5	nΑ μΑ	V _{CB} = 120V V _{CB} = 120V, T _A = +100°C
Emitter Cut-Off Current	I _{EBO}	—	<1	10	nA	$V_{EB} = 6V$
	V _{CE(sat)}	_	20	30	mV	$I_{\rm C} = 100 {\rm mA}, I_{\rm B} = 5 {\rm mA}$
		—	45	60		$I_{C} = 1A, I_{B} = 100 \text{mA}$
Collector-Emitter Saturation Voltage (Note 11)		_	50	70		$I_{\rm C} = 1$ A, $I_{\rm B} = 50$ mA
		_	100	135		$I_{\rm C} = 2A, I_{\rm B} = 50 {\rm mA}$
		—	210	260		$I_{\rm C} = 6A, I_{\rm B} = 300 {\rm mA}$
Base-Emitter Saturation Voltage (Note 11)	V _{BE(sat)}	_	1000	1100	mV	$I_{\rm C} = 6A, I_{\rm B} = 300 {\rm mA}$
Base-Emitter Turn-On Voltage (Note 11)	V _{BE(on)}	—	940	1050	mV	$I_{C} = 6A, V_{CE} = 1V$
		100	200	—		$I_{C} = 10 \text{mA}, V_{CE} = 1 \text{V}$
DC Current Gain (Note 11)	h	100	200	300		$I_{C} = 2A, V_{CE} = 1V$
DC Current Gain (Note 11)	h _{FE}	55	105	—		$I_{C} = 5A, V_{CE} = 1V$
		20	40	—		I _C = 10A, V _{CE} = 1V
Output Capacitance	Cobo	—	31	—	pF	V _{CB} = 10V. f = 1MHz
Current Gain-Bandwidth Product	f⊤	—	130	—	MHz	$V_{CE} = 5V, I_C = 100mA, f = 100MHz$
Switching Times	t _{on}	_	42	—	ns	$I_{C} = 1A, V_{CC} = 10V,$
	t _{off}	—	760	—	115	$I_{B1} = -I_{B2} = 100 \text{mA}$

Note: 11. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.



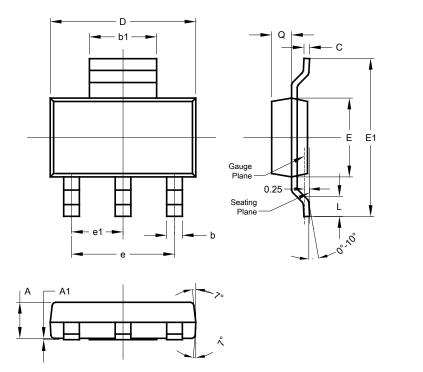
Typical Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)





Package Outline Dimensions

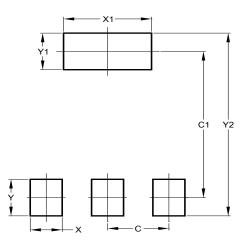
Please see http://www.diodes.com/package-outlines.html for the latest version.



1	0.01					
SOT223						
Dim	Min	Max	Тур			
Α	1.55	1.65	1.60			
A1	0.010	0.15	0.05			
b	0.60	0.80	0.70			
b1	2.90	3.10	3.00			
С	0.20	0.30	0.25			
D	6.45	6.55	6.50			
Е	3.45	3.55	3.50			
E1	6.90	7.10	7.00			
е	-	-	4.60			
e1	-	-	2.30			
L	0.85	1.05	0.95			
Q	0.84	0.94	0.89			
All [All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00



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